

KI SEMICONDUCTOR

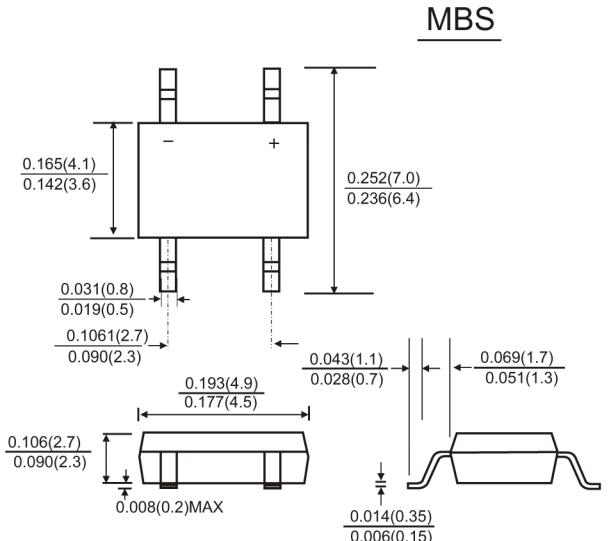
SCHOTTKY BARRIER BRIDGE RECTIFIER
Reverse Voltage - 20 to 100 Volts
Forward Current - 1.0Ampere

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

- Case: MBS molded plastic body
- Epoxy: UL94V-0 rate flame retardant
- Terminals: Plated leads solderable per MIL-STD-750,method 2026
- Mounting Position: Any
- Weight: 0.004ounce, 0.125 gram



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	MS 12	MS 13	MS 14	MS 15	MS 16	MS 18	MS 110	Volts
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	57	71	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	Volts
Maximum average forward rectified current (See Fig. 1)	I _(AV)				1.0				Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}				30				Amps
Maximum instantaneous forward voltage at 1.0 A(note 1)	V _F		0.55		0.75		0.85		Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T _A =25°C T _A =100°C				0.5				mA
	I _R				20.0				
Typical thermal resistance (Note 2)	R _{θ JA} R _{θ JL}				88.0				°C/W
Operating junction temperature range	T _J				-65 to+125				°C
Storage temperature range	T _{STG}				-65 to+150				°C

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2. P.C.B. mounted with 0.2 X 0.2"(5.0 X 5.0mm)copper pad areas

RATINGS AND CHARACTERISTIC CURVES MS12 THRU MS120

FIG.1-FORWARD CURRENT DERATING CURVE

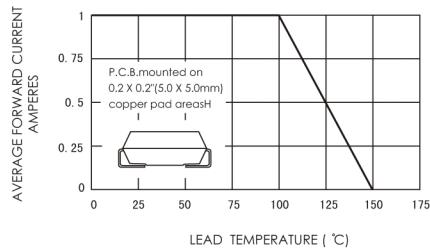


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

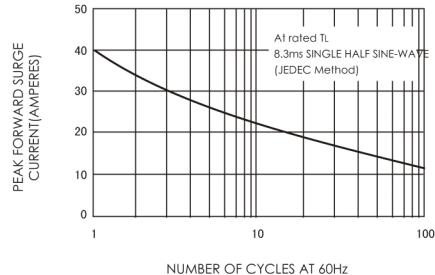


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

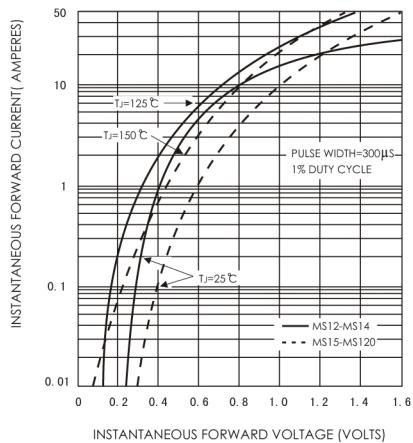


FIG.4-TYPICAL REVERSE CHARACTERISTICS

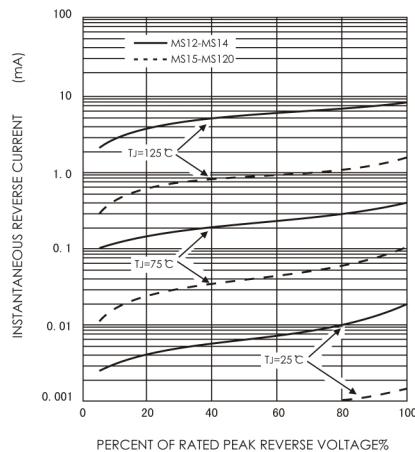


FIG.5-TYPICAL JUNCTION CAPACITANCE

